Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
C <sub>iss</sub>	Input Capacitance	V <sub>GS</sub> = 0V		3700	4440	
C <sub>oss</sub>	Output Capacitance	V <sub>DS</sub> = 25V		320	450	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	f = 1 MHz		150	225	
$Q_g$	Total Gate Charge <sup>③</sup>	V <sub>GS</sub> = 10V		190	285	
$Q_{gs}$	Gate-Source Charge	$V_{DD} = 0.5 V_{DSS}$		16	24	nC
$Q_{gd}$	Gate-Drain ("Miller") Charge	I <sub>D</sub> = I <sub>D[Cont.]</sub> @ 25°C		90	135	
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>GS</sub> = 15V		12	24	
t <sub>r</sub>	Rise Time	$V_{DD} = 0.5 V_{DSS}$		10	20	ns
t <sub>d(off)</sub>	Turn-off Delay Time	I <sub>D</sub> = I <sub>D[Cont.]</sub> @ 25°C		50	75	115
t <sub>f</sub>	Fall Time	$R_G = 1.6\Omega$		14	28	

## **SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS**

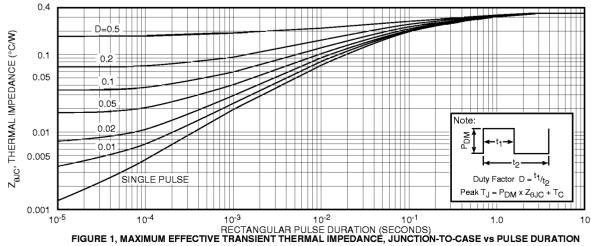
Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
I <sub>s</sub>	Continuous Source Current (Body Diode)			10	Amno
I <sub>SM</sub>	Pulsed Source Current ① (Body Diode)			40	Amps
V <sub>SD</sub>	Diode Forward Voltage $\bigcirc$ ( $V_{GS} = 0V$ , $I_{S} = -I_{D[Cont.]}$ )			1.3	Volts
t <sub>rr</sub>	Reverse Recovery Time $(I_S = -I_{D[Cont.]}, dI_S/dt = 100A/\mu s)$		850		ns
Q <sub>rr</sub>	Reverse Recovery Charge $(I_S = -I_{D[Cont.]}, dI_S/dt = 100A/\mu s)$		11		μC

## THERMAL CHARACTERISTICS

Symbol	Characteristic	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction to Case			0.34	°C/W
$R_{\thetaJA}$	Junction to Ambient			40	C/VV

 $<sup>\</sup>ensuremath{ \textcircled{\scriptsize 1}}$  Repetitive Rating: Pulse width limited by maximum junction temperature.

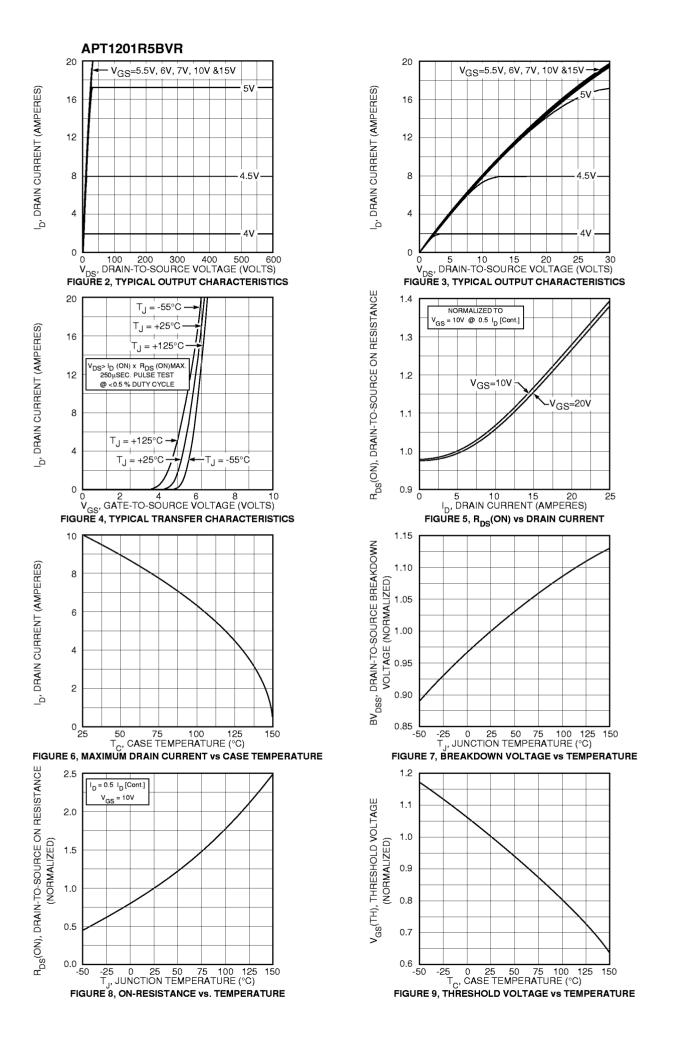
APT Reserves the right to change, without notice, the specifications and information contained herein.



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<sup>3</sup> See MIL-STD-750 Method 3471

 $<sup>\</sup>bigcirc$  Starting T<sub>i</sub> = +25°C, L = 26mH, R<sub>G</sub> = 25Ω, Peak I<sub>L</sub> = 10A



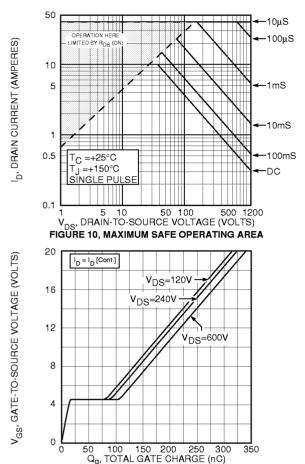
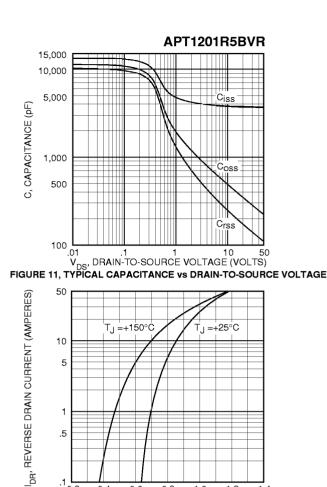


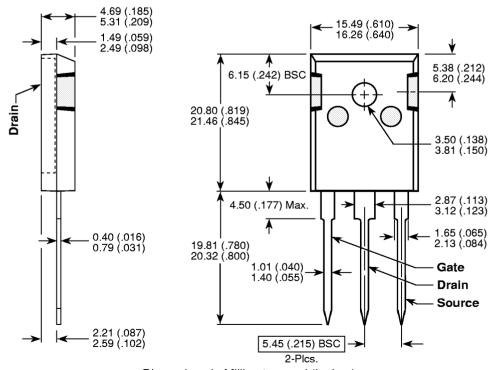
FIGURE 12, GATE CHARGES vs GATE-TO-SOURCE VOLTAGE



V<sub>SD</sub>, SOURCE-TO-DRAIN VOLTAGE (VOLTS)

FIGURE 13, TYPICAL SOURCE-DRAIN DIODE FORWARD VOLTAGE

## **TO-247 Package Outline**



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